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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Raina et al.
Appl. No. : 10/644,443
Filed : August 19, 2003
For : NITROGEN AND
PHOSPHOROUS DOPED
AMORPHOUS SILICON AS
RESISTOR FOR FIELD
EMISSION DISPLAY DEVICE
BASEPLATE
Examiner : Roy, Sikha
Group Art Unit : 2879

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being mailed via Express Mail #EV 309079712 US in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

February 1, 2005

(Date)
Sabin H. Lee, Reg. No. 43,745

RESPONSE TO OFFICE ACTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed on December 1, 2004, please amend the above-captioned application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.

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